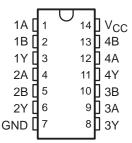
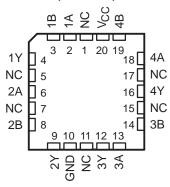
- Operating Voltage Range of 4.5 V to 5.5 V
- Outputs Can Drive Up To 10 LSTTL Loads
- Low Power Consumption, 20-μA Max I_{CC}

SN54HCT00 . . . J OR W PACKAGE SN74HCT00 . . . D, DB, N, NS, OR PW PACKAGE (TOP VIEW)



- Typical t_{pd} = 10 ns
- ±4-mA Output Drive at 5 V
- Low Input Current of 1 μA Max
- Inputs Are TTL-Voltage Compatible





NC - No internal connection

description/ordering information

These devices contain four independent 2-input NAND gates. They perform the Boolean function $Y = \overline{A} \cdot \overline{B}$ or $Y = \overline{A} + \overline{B}$ in positive logic.

ORDERING INFORMATION

TA	PACKAGET		ORDERABLE PART NUMBER	TOP-SIDE MARKING
	PDIP – N	Tube of 25	SN74HCT00N	SN74HCT00N
		Tube of 50	SN74HCT00D	
	SOIC - D	Reel of 2500	SN74HCT00DR	HCT00
		Reel of 250	SN74HCT00DT	
–40°C to 85°C	SOP - NS	Reel of 2000	SN74HCT00NSR	HCT00
	SSOP – DB	Reel of 2000	SN74HCT00DBR	HT00
		Tube of 90	SN74HCT00PW	
	TSSOP – PW	Reel of 2000	SN74HCT00PWR	HT00
		Reel of 250	SN74HCT00PWT	
	CDIP – J	Tube of 25	SNJ54HCT00J	SNJ54HCT00J
–55°C to 125°C	CFP – W	Tube of 150	SNJ54HCT00W	SNJ54HCT00W
	LCCC – FK	Tube of 55	SNJ54HCT00FK	SNJ54HCT00FK

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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FUNCTION TABLE (each gate)

INP	JTS	OUTPUT
Α	В	Υ
Н	Н	L
L	X	Н
Х	L	Н

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}		–0.5 V to 7 V
Input clamp current, I_{IK} ($V_I < 0$ or $V_I > V_{CC}$) (se	e Note 1)	±20 mA
Output clamp current, IOK (VO < 0 or VO > VCC	;) (see Note 1)	±20 mA
Continuous output current, I_O ($V_O = 0$ to V_{CC})		±25 mA
Continuous current through V _{CC} or GND		±50 mA
Package thermal impedance, θ _{JA} (see Note 2):	D package	86°C/W
	DB package	96°C/W
	N package	80°C/W
	NS package	76°C/W
	PW package	113°C/W
Storage temperature range, T _{stg}		–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions (see Note 3)

			SI	N54HCT	00	SN	174HCT0	0	UNIT
			MIN	NOM	MAX	MIN	NOM	MAX	UNIT
Vcc	Supply voltage		4.5	5	\$ 5.5	4.5	5	5.5	V
VIH	High-level input voltage	V _{CC} = 4.5 V to 5.5 V	2	Š	,/	2			V
\vee_{IL}	Low-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		72/2	0.8			0.8	V
٧ _I	Input voltage		0	1	VCC	0		VCC	V
٧o	Output voltage		0	2	VCC	0		VCC	V
Δt/Δv Input transition rise/fall time		0~)*	500			500	ns	
T _A Operating free-air temperature		-55		125	-40		85	°C	

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

^{2.} The package thermal impedance is calculated in accordance with JESD 51-7.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		Vaa	T _A = 25°C			SN54HCT00		SN74HCT00		UNIT
PARAMETER			vcc	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
Vari	VI = VIH or VIL	I _{OH} = -20 μA	4.5 V	4.4	4.499		4.4		4.4		V
VOH	AI = AIH OL AIL	$I_{OH} = -4 \text{ mA}$	4.5 V	3.98	4.3		3.7		3.84]
Voi	\/ı = \/ or \/	I _{OL} = 20 μA	4.5 V		0.001	0.1		0.1		0.1	V
VOL	VI = VIH or VIL	$I_{OL} = 4 \text{ mA}$			0.17	0.26		0.4		0.33	'
lį	$V_I = V_{CC}$ or 0		5.5 V		±0.1	±100		±1000		±1000	nA
Icc	$V_I = V_{CC}$ or 0,	I _O = 0	5.5 V			2	ζ),	40		20	μΑ
ΔI _{CC} †	One input at 0.5 V one of the of the orest o		5.5 V		1.4	2.4	900	3		2.9	mA
Ci			4.5 V to 5.5 V		3	10	4	10		10	pF

[†] This is the increase in supply current for each input that is at one of the specified TTL voltage levels, rather than 0 V or VCC.

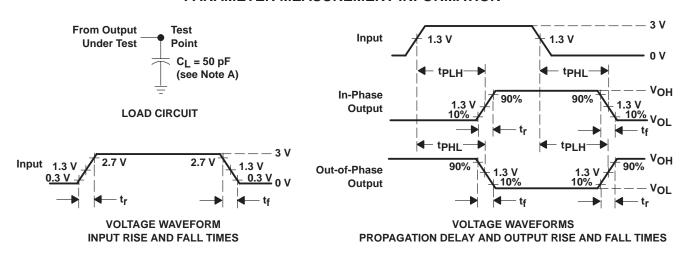
switching characteristics over recommended operating free-air temperature range, C_L = 50 pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	TO (OUTPUT)	Vaa	T,	չ = 25°C	;	SN54HCT00	SN74I	HCT00	UNIT
	(INPUT)		VCC	MIN	TYP	MAX	MIN MA	MIN	MAX	UNII
t _{pd} A or B	A or D	Y	4.5 V		11	20	<u></u>)	25	20
	AUB		5.5 V		10	18	01/2/2	7	22	ns
t _t		Y	4.5 V		9	15	P. C. 2	2	19	
			5.5 V		8	14	2)	17	ns

operating characteristics, T_A = 25°C

PARAMETER		TEST CONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance per gate	No load	20	pF

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and test-fixture capacitance.

- B. Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \Omega$, $t_r = 6$ ns, $t_f = 6$ ns.
- C. The outputs are measured one at a time with one input transition per measurement.
- D. tplH and tpHL are the same as tpd.

Figure 1. Load Circuit and Voltage Waveforms

